

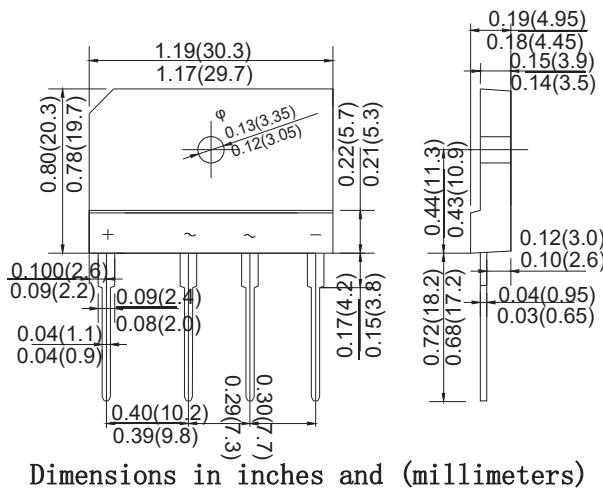
KBJ SILICON BRIDGE RECTIFIERV

FEATURES

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- Construction utilizes void-free molded plastic technique
- High reliability
- High temperature soldering guaranteed: 260 °C/10 seconds at terminals
- Component in accordance to RoHS 2015/863 and WEEE 2012/19/EU

MECHANICAL DATA

- Case style: KBJ molded plastic
- Mounting position: Any



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		KBJ 4A	KBJ 4B	KBJ 4D	KBJ 4G	KBJ 4J	KBJ 4K	KBJ 4M	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forward Output current @ $T_A=100^\circ\text{C}$	$I_{F(AV)}$	4.0						A	
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load	I_{FSM}	150.0						A	
Maximum instantaneous forward voltage at 2.0 A	V_F	1.0						V	
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=100^\circ\text{C}$	I_R	10.0 1.0						μA mA	
Typical junction capacitance per element	C_J	45						pF	
Typical thermal resistance	$R_{\theta JC}$	2.2						$^\circ\text{C}/\text{W}$	
Operating junction temperature range	T_J	-55 ---- +150						$^\circ\text{C}$	
Storage temperature range	T_{STG}	-55 ---- +150						$^\circ\text{C}$	

RATINGS AND CHARACTERISTIC CURVES

FIG.1 – PEAK FORWARD SURGE CURRENT

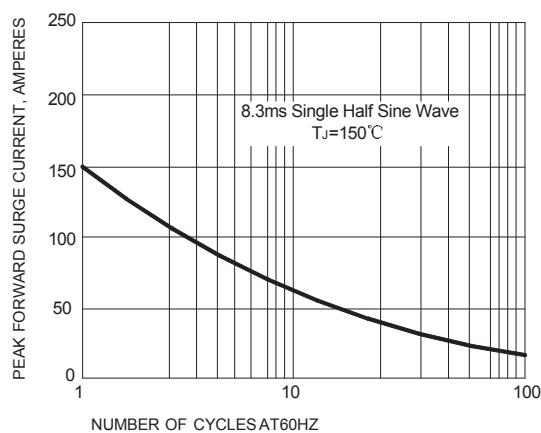


FIG.2 – FORWARD DERATING CURVE

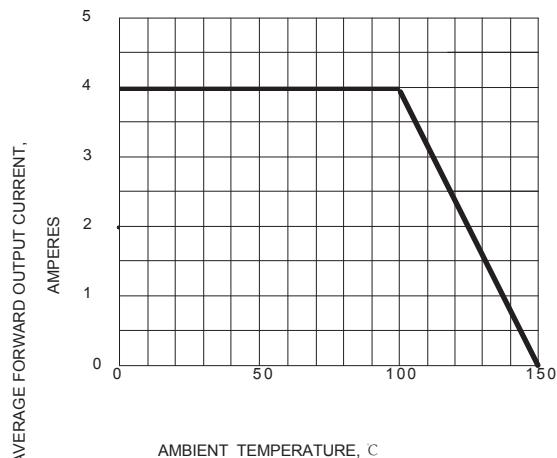


FIG.3 -- TYPICAL FORWARD CHARACTERISTIC

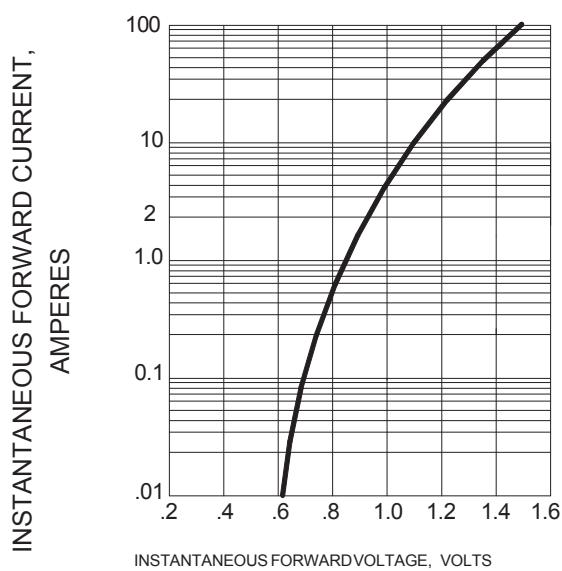


FIG.4 -- TYPICAL JUNCTION CAPACITANCE

